Ordering number : EN2191A

SANYO

No.2191A

# SB0030-01A

Schottky Barrier Diode

10V, 30mA Detection Applications

### Features

- · Glass sleeve structure
- · Detection efficiency: 70%
- · Small size (Half the size of the DO-35 heretofore in use)

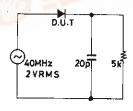
## Absolute Maximum Ratings at Ta = 25°C

so to to material and letterings at		unit	
Reverse Voltage	$V_R$	-10	V
Average Rectified Current	$I_{O}$	30	mÅ
Junction Temperature	Ti	100	00
Storage Temperature	Tstg		°C
8	100g	-55  to  + 100	-0

### Electrical Characteristics at Ta = 25°C

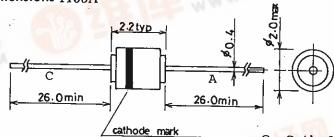
control offar acteristics at 1a = 25 C			min t	yp max	unit
Forward Current	$I_{\mathbb{P}}$	$V_{\rm F} = 1.0 V$	4.5	) P man	
Reverse Current	Ī,		4.0		mA
	1R	$V_R = -6V$		-70	μA
Capacitance	C	$V_R = -1V_f = 1MHz$		1.5	ρF
Detection Efficiency	n	f = 40MHz	<b>5</b> 0	1.0	A
2010101	-1	1-40141115	70		%

### Detection Efficiency Circuit



Unit (resistance: Ω, capacitance: F)

Package Dimensions 1153A (unit: mm)



C: Cathode
A: Anode

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